

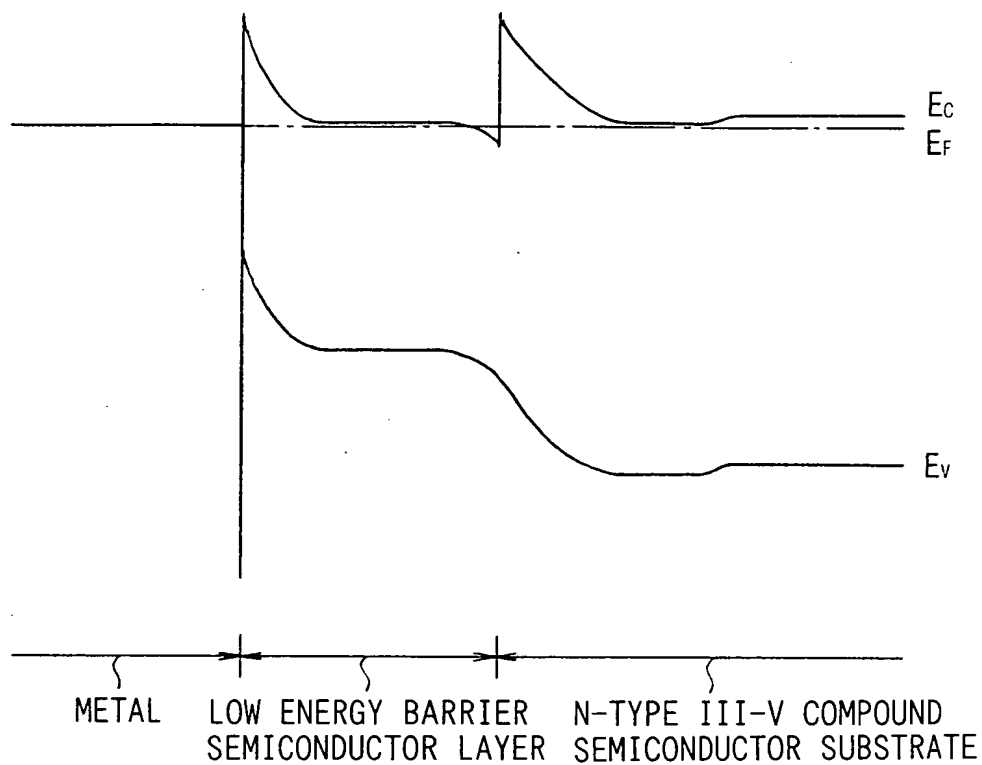
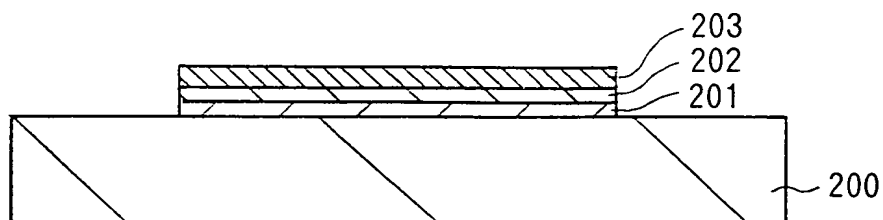
Fig. 2*Fig. 3*

Fig. 4A

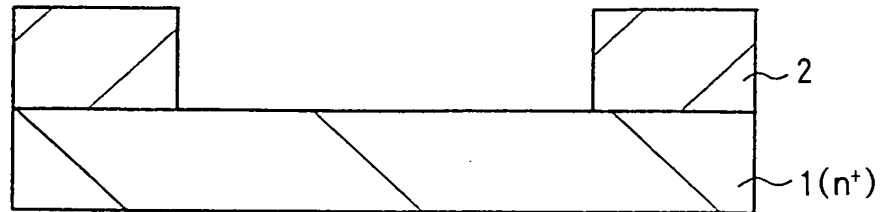


Fig. 4B

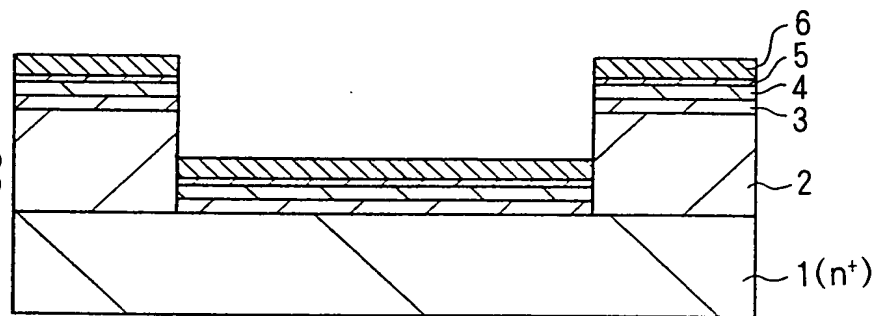


Fig. 4C

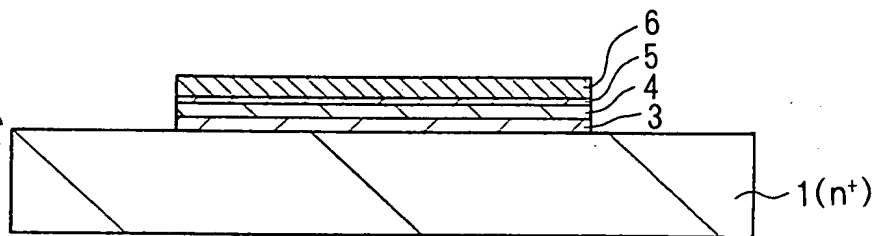


Fig. 4D

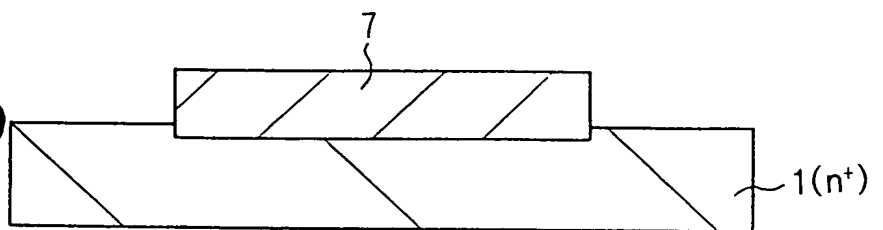


Fig. 5

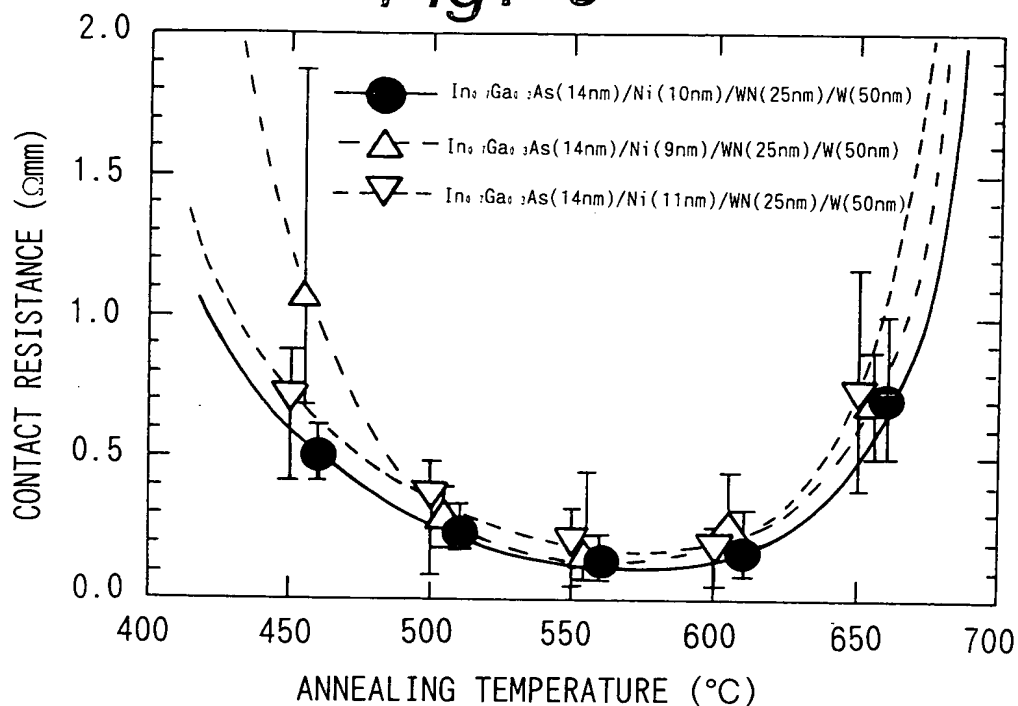


Fig. 7

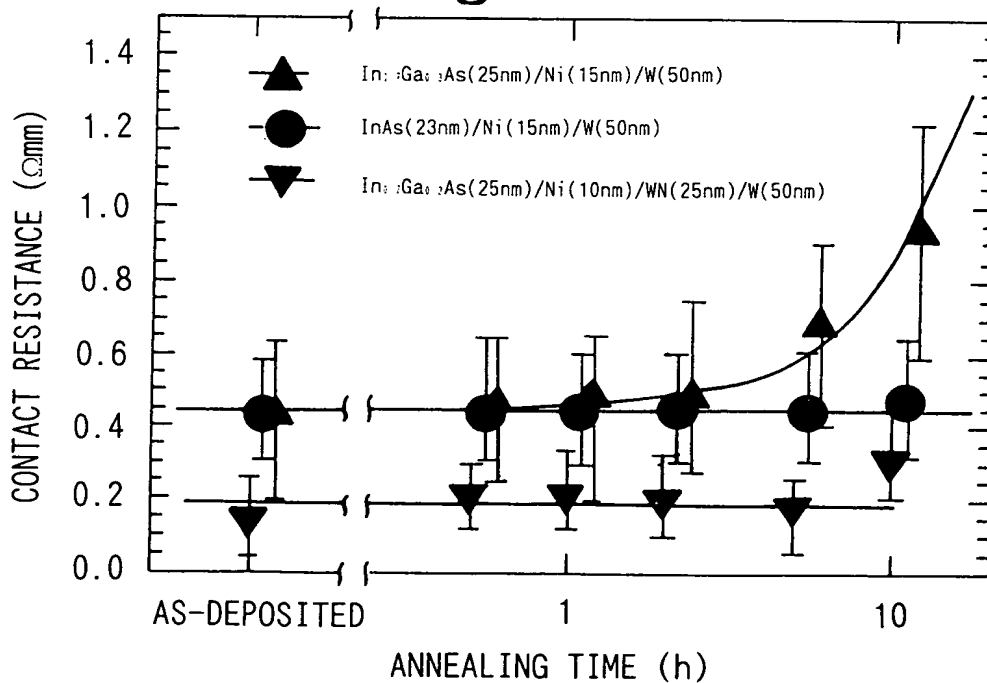
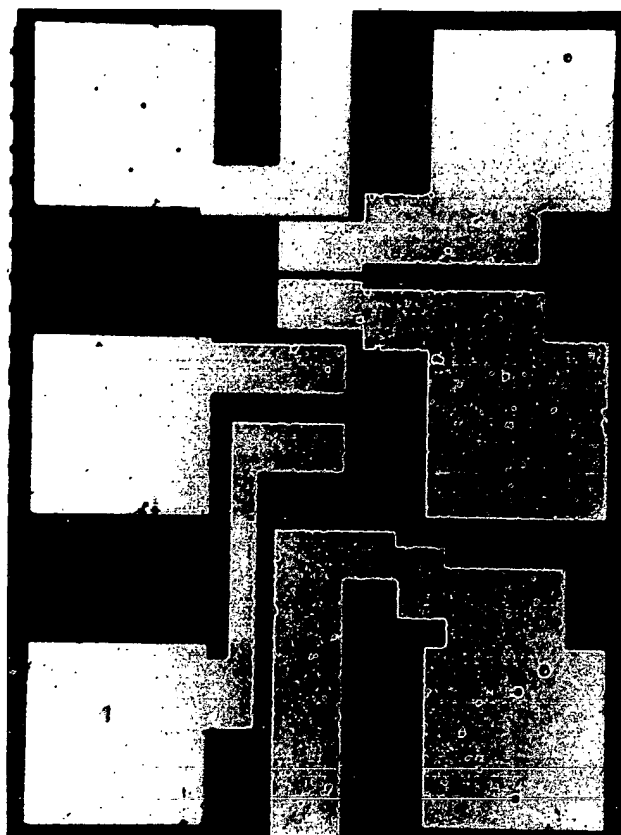
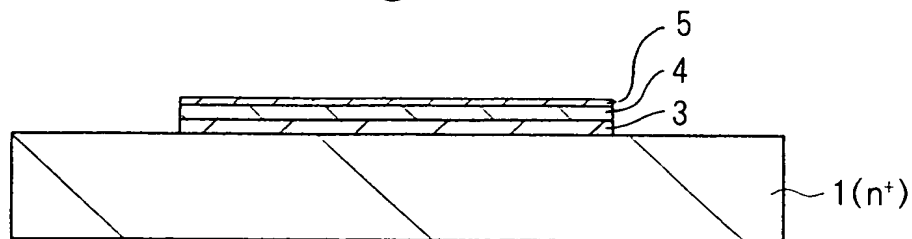
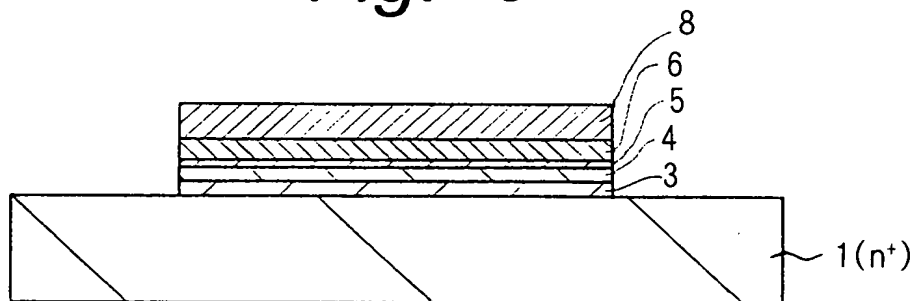
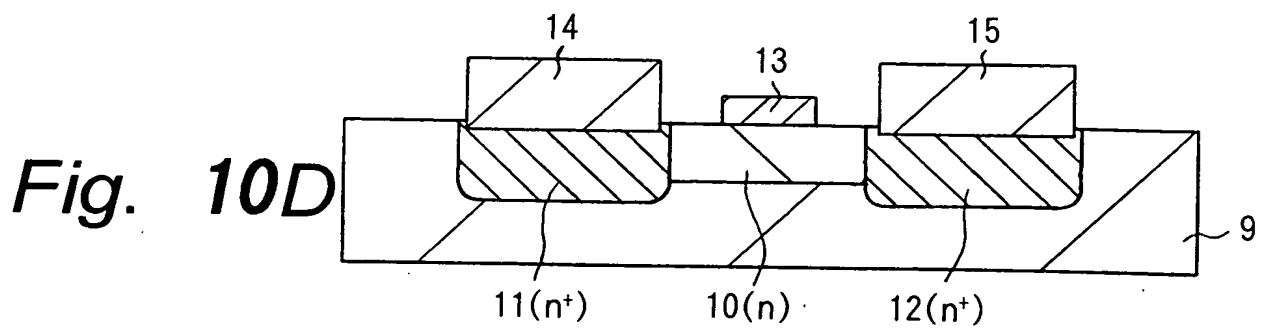
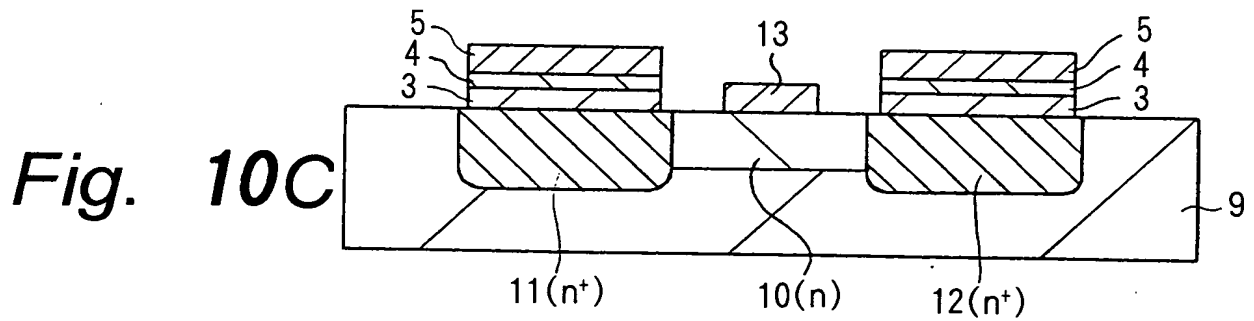
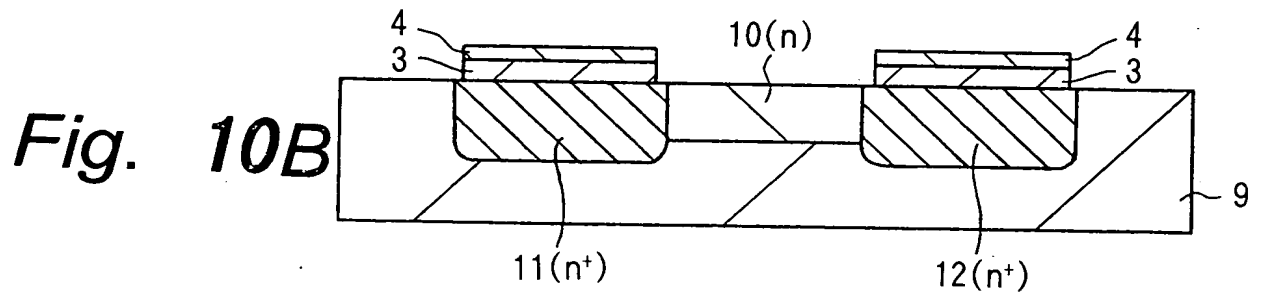
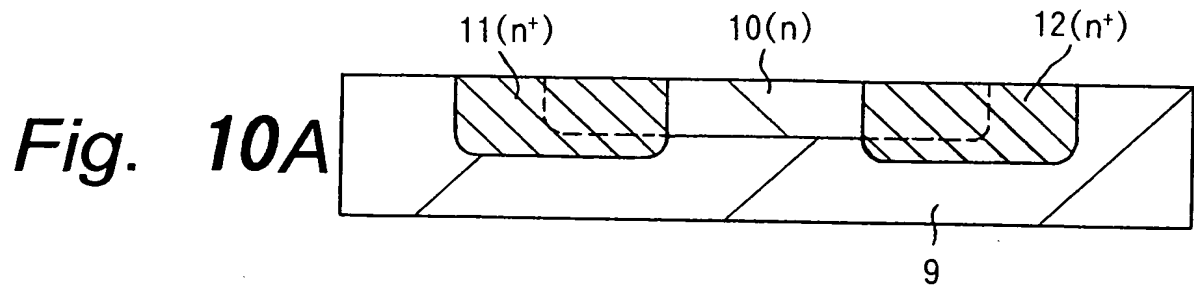


Fig. 6

50µm

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Fig. 8*Fig. 9*



- 1: n⁺-TYPE GaAs SUBSTRATE
- 3: NON-SINGLE CRYSTAL In_{0.7}Ga_{0.3}As LAYER
- 4: Ni FILM
- 5: WN FILM
- 6: W FILM
- 7: OHMIC ELECTRODE
- 8: Al FILM